

APT5020BNR 500V 28.0A 0.20Ω

APT5022BNR 500V 27.0A 0.22Ω

POWER MOS IV®

UIS RATED

N-CHANNEL ENHANCEMENT MODE HIGH VOLTAGE POWER MOSFETS

MAXIMUM RATINGS

All Ratings: $T_C = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	APT5020BNR	APT5022BNR	UNIT
V_{DSS}	Drain-Source Voltage	500	500	Volts
I_D	Continuous Drain Current @ $T_C = 25^\circ\text{C}$	28	27	Amps
I_{DM}	Pulsed Drain Current ^①	112	108	
V_{GS}	Gate-Source Voltage Continuous	±20		Volts
V_{GSM}	Gate-Source Voltage Transient	±30		
P_D	Total Power Dissipation @ $T_C = 25^\circ\text{C}$	360		Watts
	Linear Derating Factor	2.9		W/°C
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to 150		°C
T_L	Lead Temperature: 0.063" from Case for 10 Sec.	300		
I_{AR}	Avalanche Current ^① (Repetitive and Non-Repetitive)	28		Amps
E_{AR}	Repetitive Avalanche Energy ^①	30		mJ
E_{AS}	Single Pulse Avalanche Energy ^④	1300		

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage ($V_{GS} = 0V, I_D = 250 \mu\text{A}$)	500			Volts
$I_{D(ON)}$	On State Drain Current ^② ($V_{DS} > I_{D(ON)} \times R_{DS(ON)}$ Max, $V_{GS} = 10V$)	APT5020BNR	28		Amps
		APT5022BNR	27		
$R_{DS(ON)}$	Drain-Source On-State Resistance ^② ($V_{GS} = 10V, 0.5 I_D$ [Cont.])	APT5020BNR		0.20	Ohms
		APT5022BNR		0.22	
I_{DSS}	Zero Gate Voltage Drain Current ($V_{DS} = V_{DSS}, V_{GS} = 0V$)			250	μA
	Zero Gate Voltage Drain Current ($V_{DS} = 0.8 V_{DSS}, V_{GS} = 0V, T_C = 125^\circ\text{C}$)			1000	
I_{GSS}	Gate-Source Leakage Current ($V_{GS} = \pm 20V, V_{DS} = 0V$)			±100	nA
$V_{GS(TH)}$	Gate Threshold Voltage ($V_{DS} = V_{GS}, I_D = 1.0\text{mA}$)	2		4	Volts

THERMAL CHARACTERISTICS

Symbol	Characteristic	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to Case			0.34	°C/W
$R_{\theta JA}$	Junction to Ambient			40	

CAUTION: These Devices are Sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

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DYNAMIC CHARACTERISTICS

APT5020/5022BNR

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
C_{iss}	Input Capacitance	$V_{GS} = 0V$		3610		pF
C_{oss}	Output Capacitance	$V_{DS} = 25V$		602		
C_{rss}	Reverse Transfer Capacitance	$f = 1\text{ MHz}$		248		
Q_g	Total Gate Charge ③	$V_{GS} = 10V$		182		nC
Q_{gs}	Gate-Source Charge	$V_{DD} = 0.5 V_{DSS}$		20		
Q_{gd}	Gate-Drain ("Miller") Charge	$I_D = I_D[\text{Cont.}] @ 25^\circ\text{C}$		105		
$t_{d(on)}$	Turn-on Delay Time	$V_{GS} = 15V$		21		ns
t_r	Rise Time	$V_{DD} = 0.5 V_{DSS}$		43		
$t_{d(off)}$	Turn-off Delay Time	$I_D = I_D[\text{Cont.}] @ 25^\circ\text{C}$		119		
t_f	Fall Time	$R_G = 1.8\Omega$		64		

SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
I_S	Continuous Source Current (Body Diode)	APT5020BNR		28	Amps
		APT5022BNR		27	
I_{SM}	Pulsed Source Current ① (Body Diode)	APT5020BNR		112	Amps
		APT5022BNR		108	
V_{SD}	Diode Forward Voltage ② ($V_{GS} = 0V, I_S = -I_D[\text{Cont.}]$)			1.3	Volts
t_{rr}	Reverse Recovery Time ($I_S = -I_D[\text{Cont.}], dI_S/dt = 100A/\mu s$)	215	430	860	ns
Q_{rr}	Reverse Recovery Charge ($I_S = -I_D[\text{Cont.}], dI_S/dt = 100A/\mu s$)	3	7	14	μC

SAFE OPERATING AREA CHARACTERISTICS

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
SOA1	Safe Operating Area	$V_{DS} = 0.4 V_{DSS}, I_{DS} = P_D / 0.4 V_{DSS}, t = 1\text{ Sec.}$	360			Watts
SOA2	Safe Operating Area	$I_{DS} = I_D[\text{Cont.}], V_{DS} = P_D / I_D[\text{Cont.}], t = 1\text{ Sec.}$	360			
I_{LM}	Inductive Current Clamped	APT5020BNR	112			Amps
		APT5022BNR	108			

① Repetitive Rating: Pulse width limited by maximum junction temperature.

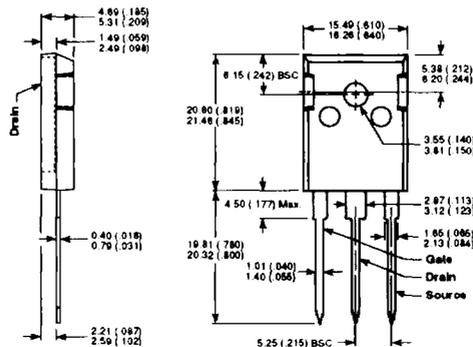
③ See MIL-STD-750 Method 3471

② Pulse Test: Pulse width < 380 μs , Duty Cycle < 2%

④ Starting $T_j = +25^\circ\text{C}$, $L = 3.3\text{ mH}$, $R_G = 25\Omega$, Peak $I_L = 28\text{ A}$

APT Reserves the right to change, without notice, the specifications and information contained herein.

TO-247AD Package Outline



Dimensions in Millimeters and (Inches)